

# 12 A Three-quadrant triacs high commutation Rev. 01 — 12 April 2007

**Product data sheet** 

## **Product profile**

## 1.1 General description

Passivated, new generation, high commutation triacs in a SOT404 plastic single-ended surface-mountable package

#### 1.2 Features

- Very high commutation performance maximized at each gate sensitivity
- High immunity to dV/dt

## 1.3 Applications

- High power motor control e.g. washing
   Non-linear rectifier-fed motor loads machines, vacuum cleaners
- Refrigeration and air conditioning compressors
- Electronic thermostats

#### 1.4 Quick reference data

- $V_{DRM} \le 600 \text{ V (BTA312B-600B/C)}$
- $V_{DRM} \le 800 \text{ V (BTA312B-800B/C)}$
- $I_{TSM} \le 95 \text{ A (t = 20 ms)}$
- I<sub>GT</sub> ≤ 50 mA (BTA312B series B)
- $I_{GT} \le 35 \text{ mA (BTA312B series C)}$
- $I_{T(RMS)} \le 12 A$

## **Pinning information**

Table 1. **Pinning** 

Pin	Description	Simplified outline	Symbol
1	main terminal 1 (T1)		N 1
2	main terminal 2 (T2)	mb	T2—T1
3	gate (G)		sym051
mb	mounting base; main terminal 2 (T2)		
		SOT404 (D2PAK)	



## 3. Ordering information

#### Table 2. Ordering information

Type number	Package				
	Name	Description	Version		
BTA312B-600B	D2PAK	K plastic single-ended surface-mounted package (D2PAK); 3-leads (one lead cropped)	SOT404		
BTA312B-600C					
BTA312B-800B					
BTA312B-800C					

# 4. Limiting values

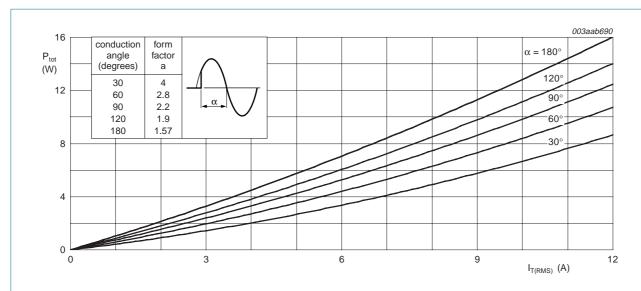
#### Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DRM}$	repetitive peak off-state voltage	BTA312B-600B; BTA312B-600C	<u>[1]</u> -	600	V
		BTA312B-800B; BTA312B-800C	-	800	V
$I_{T(RMS)}$	RMS on-state current	full sine wave; $T_{mb} \le 101$ °C; see Figure 4 and 5	-	12	Α
I <sub>TSM</sub>	non-repetitive peak on-state current	full sine wave; $T_j = 25$ °C prior to surge; see Figure 2 and 3			
		t = 20 ms	-	95	Α
		t = 16.7 ms	-	105	Α
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t = 10 ms	-	45	A <sup>2</sup> s
dI <sub>T</sub> /dt	rate of rise of on-state current	$I_{TM} = 20 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu\text{s}$	-	100	A/μs
I <sub>GM</sub>	peak gate current		-	2	Α
$P_{GM}$	peak gate power		-	5	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	0.5	W
T <sub>stg</sub>	storage temperature		-40	+150	°C
Tj	junction temperature		-	125	°C

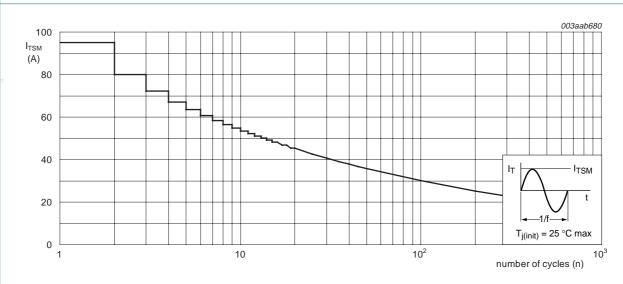
<sup>[1]</sup> Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 A/µs.

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 $\alpha = \text{conduction angle}$ 

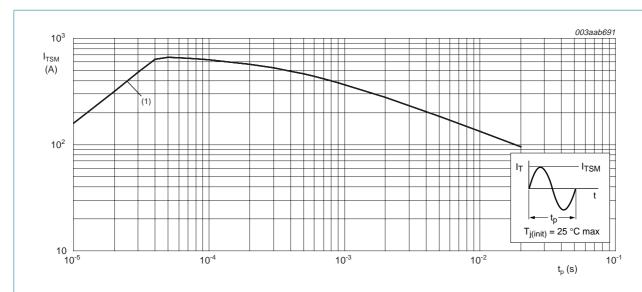
Fig 1. Total power dissipation as a function of RMS on-state current; maximum values



f = 50 Hz

Fig 2. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

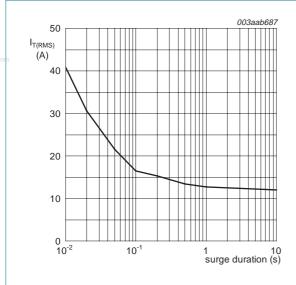
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 $t_p \le 20 \text{ ms}$ 

(1) dl<sub>T</sub>/dt limit

Fig 3. Non-repetitive peak on-state current as a function of pulse duration; maximum values



f = 50 Hz

T<sub>mb</sub> = 101 °C

Fig 4. RMS on-state current as a function of surge duration; maximum values

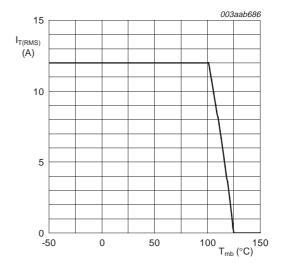
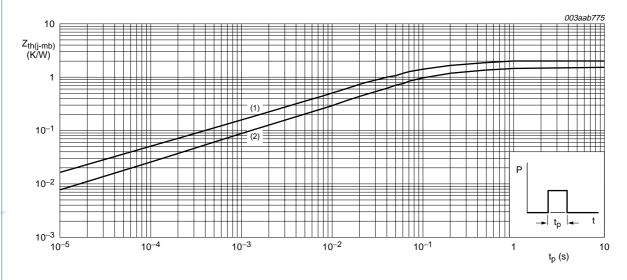


Fig 5. RMS on-state current as a function of mounting base temperature; maximum values

## 5. Thermal characteristics

Table 4. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	half cycle; see Figure 6	-	-	2.0	K/W
		full cycle; see Figure 6	-	-	1.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	mounted on a printed circuit board; minimum footprint	-	55	-	K/W



- (1) Unidirectional (half cycle)
- (2) Bidirectional (full cycle)

Fig 6. Transient thermal impedance from junction to mounting base as a function of pulse duration

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## 6. Static characteristics

Table 5. Static characteristics

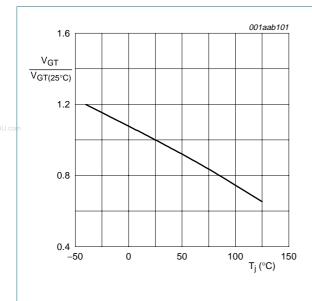
 $T_i = 25 \,^{\circ}C$  unless otherwise specified.

Symbol	Parameter	Conditions		BTA312B-600B BTA312B-800B			BTA312B-600C BTA312B-800C		
			Min	Тур	Max	Min	Тур	Max	
$I_{GT}$	gate trigger	$V_D = 12 \text{ V; } I_T = 0.1 \text{ A; see } \frac{\text{Figure 8}}{}$							
	current	T2+ G+	2	-	50	2	-	35	mΑ
		T2+ G-	2	-	50	2	-	35	mΑ
		T2- G-	2	-	50	2	-	35	mA
I <sub>L</sub>	latching current	V <sub>D</sub> = 12 V; I <sub>GT</sub> = 0.1 A; see <u>Figure 10</u>							
		T2+ G+	-	-	60	-	-	50	mA
		T2+ G-	-	-	90	-	-	60	mΑ
		T2- G-	-	-	60	-	-	50	mΑ
$I_{H}$	holding current	$V_D = 12 \text{ V; } I_{GT} = 0.1 \text{ A; see } \frac{\text{Figure } 11}{}$	-	-	60	-	-	35	mΑ
$V_{T}$	on-state voltage	I <sub>T</sub> = 15 A; see <u>Figure 9</u>	-	1.3	1.6	-	1.3	1.6	V
	gate trigger voltage	$V_D = 12 \text{ V; } I_T = 0.1 \text{ A; see } \frac{\text{Figure 7}}{}$	-	8.0	1.5	-	8.0	1.5	V
		$V_D = 400 \text{ V}; I_T = 0.1 \text{ A}; T_j = 125 ^{\circ}\text{C}$	0.25	0.4	-	0.25	0.4	-	V
I <sub>D</sub>	off-state current	$V_D = V_{DRM(max)}$ ; $T_j = 125  ^{\circ}C$	-	0.1	0.5	-	0.1	0.5	mΑ

## 7. Dynamic characteristics

Table 6. Dynamic characteristics

Symbol	Parameter	Conditions	BTA312B-600B BTA312B-800B			BTA312B-600C BTA312B-800C			Unit
				Тур	Max	Min	Тур	Max	
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM} = 0.67 \times V_{DRM(max)}$ ; $T_j = 125$ °C; exponential waveform; gate open circuit	1000	2000	-	500	-	-	V/μs
dl <sub>com</sub> /dt	rate of change of commutating current	$V_{DM} = 400 \text{ V}; T_j = 125 ^{\circ}\text{C}; I_{T(RMS)} = 12 \text{ A};$ without snubber; gate open circuit	30	-	-	20	-	-	A/ms
t <sub>gt</sub>	gate-controlled turn-on time	$I_{TM}$ = 20 A; $V_D$ = $V_{DRM(max)}$ ; $I_G$ = 0.1 A; $dI_G/dt$ = 5 A/ $\mu s$	-	2	-	-	2	-	μs



3 001aac669

I<sub>GT</sub>

I<sub>GT(25°C)</sub>

2 (2)

(3)

1 T<sub>j</sub> (°C)

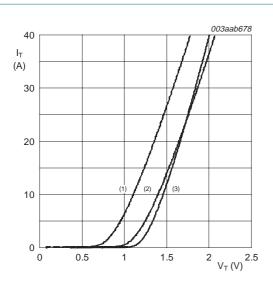
150

- (1) T2-G-
- (2) T2+ G-
- (3) T2+ G+

Fig 7. Normalized gate trigger voltage as a function of junction temperature

Fig 8. Normalized gate trigger current as a function of junction temperature

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 $V_o = 1.127 \text{ V}$  $R_s = 0.027 \Omega$ 

- (1)  $T_i = 125$  °C; typical values
- (2)  $T_j = 125 \,^{\circ}C$ ; maximum values
- (3)  $T_j = 25$  °C; maximum values

Fig 9. On-state current as a function of on-state voltage

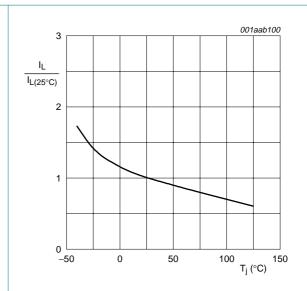


Fig 10. Normalized latching current as a function of junction temperature

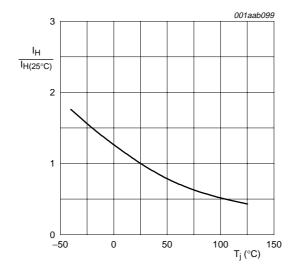


Fig 11. Normalized holding current as a function of junction temperature

## 8. Package outline

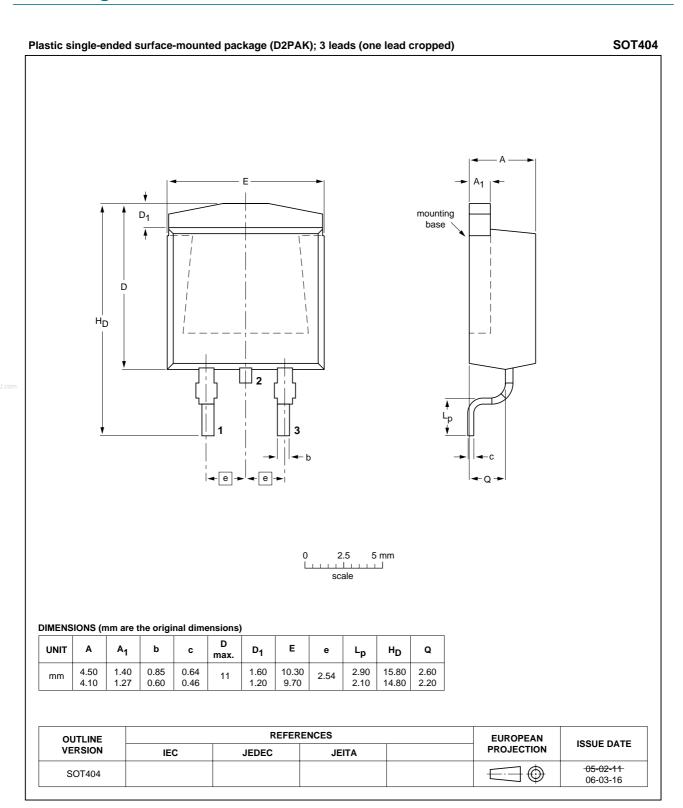


Fig 12. Package outline SOT404 (D2PAK)

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# 9. Revision history

## Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BTA312B_SER_B_C_1	20070412	Product data sheet	-	-

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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## **NXP Semiconductors**

# BTA312B series B and C

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